


	<h2 style="color: red;">FQP5N60C</h2>
	<p><b>Hersteller-Teilenummer:</b> FQP5N60C</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 600V 4.5A TO-220</p> <p><b>Datenblätter:</b>  1.FQP5N60C.pdf  2.FQP5N60C.pdf</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 43504 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQP5N60C
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 4.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	43504 pcs Stock
Hersteller Standard Vorlaufzeit	6 Weeks
detaillierte Beschreibung	N-Channel 600V 4.5A (Tc) 100W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	100W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	2.5 Ohm @ 2.25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	670pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQP5N60C ist neu im Original, Suche FQP5N60C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP5N60C AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP5N60C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>FQP5N60C</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 4.5A TO-220</p>	 <p><b>FQP5N50C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 5A TO-220</p>	 <p><b>FQP5N60</b> FAIRCHILD FQP5N60 FAIRCHILD</p>	 <p><b>FQP5N80</b> Fairchild/ON Semiconductor MOSFET N-CH 800V 4.8A TO-220</p>
 <p><b>FQP5N80C</b> Fairchild/ON Semiconductor FQP5N80C FAIRCHILD</p>	 <p><b>FQP5N50</b> KERSEMI FQP5N50 KERSEMI</p>	 <p><b>FQP5N90</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 5.4A TO-220</p>	 <p><b>FQP5N90</b> Fairchild/ON Semiconductor MOSFET N-CH 900V 5.4A TO-220</p>

### heiße Teile

Mehr

 FQP47P06_SW82049	 FQP47P06_SW82049	 FQP4N20L	 FQP4N20L	 FQP4N60C
 FQP4N65C	 FQP4N90C	 FQP4N90C	 FQP50N03	 FQP50N03C
 FQP50N06	 FQP50N06	 FQP50N06L	 FQP50N06L	 FQP50N08
 FQP55N06	 FQP55N06	 FQP55N10	 FQP55N10	 FQP58N08
 FQP58N08	 FQP5N20L	 FQP5N20L	 FQP5N50C	 FQP5N50C
 FQP5N60C	 FQP630TSTU	 FQP630TSTU	 FQP65N06	 FQP65N06
 FQP6N40C	 FQP6N40C	 FQP6N40CF	 FQP6N40CF	 FQP6N50C
 FQP6N50C	 FQP6N60C	 FQP6N60C	 FQP6N80C	 FQP6N80C
 FQP6N90C	 FQP6N90C	 FQP70N03L	 FQP70N06	 FQP70N06C
 FQP70N08	 FQP70N08	 FQP70N10	 FQP70N10	 FQP7N10L

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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